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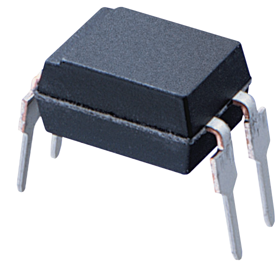
Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

PC8110xNSZ0F Series

DIP 4pin High Speed under High Load Resistance Photocoupler



■ Description

PC8110xNSZ0F Series contains an IRED optically coupled to a phototransistor built-in schottky barrier diode.

It is packaged in a 4-pin DIP, and SMT gullwing lead-form option.

Input-output isolation voltage(rms) is 5.0kV.

CTR is 50% to 400% at input current of 5mA.

■ Features

1. 4pin DIP package
2. Double transfer mold package (Ideal for Flow Soldering)
3. High speed response at turn-off time due to built-in schottky barrier diode (at saturation mode)
4. High isolation voltage between input and output ($V_{iso(rms)}$: 5kV)
5. Lead-free and RoHS directive compliant

■ Agency approvals/Compliance

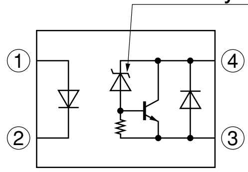
1. Recognized by UL1577 (Double protection isolation), file No. E64380 (as model No. **PC8110**)
2. Package resin : UL flammability grade (94V-0)

■ Applications

1. Home appliances

Sheet No.: D2-A03802EN
Date Jun. 30. 2005

■ Internal Connection Diagram

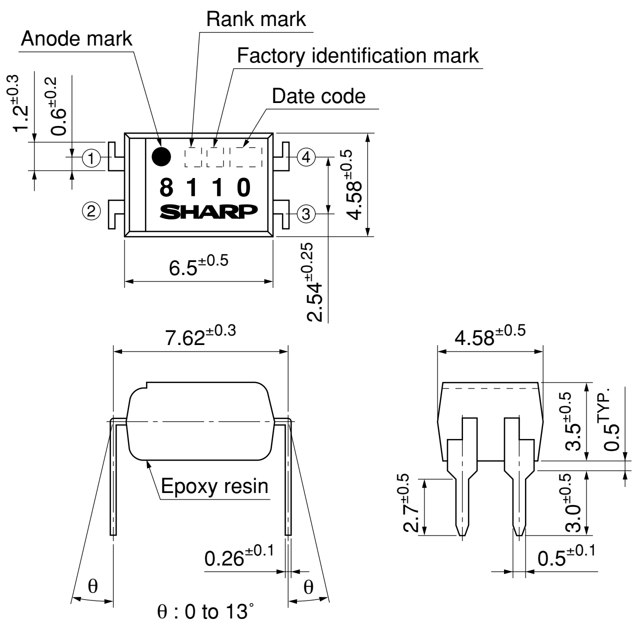


① Anode
③ Cathode
④ Emitter
⑤ Collector

■ Outline Dimensions

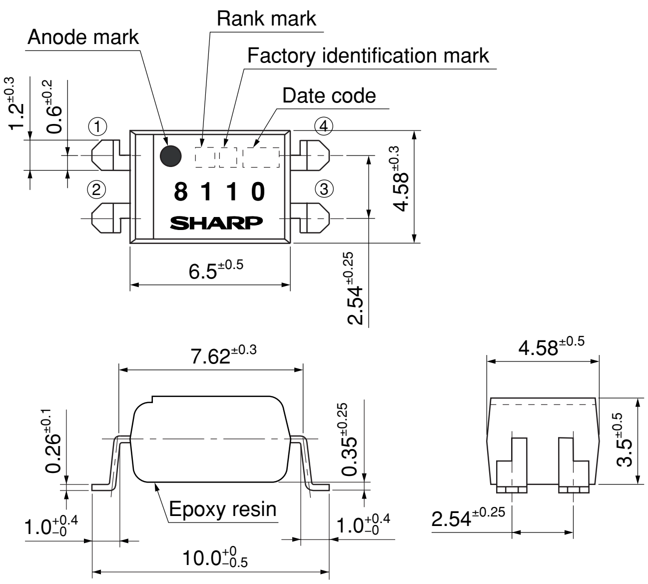
(Unit : mm)

1. Through-Hole [ex. **PC8110xNSZ0F**]



Product mass : approx. 0.23g

2. SMT Gullwing Lead-Form [ex. **PC8110xNIZ0F**]



Product mass : approx. 0.22g

Plating material : SnCu (Cu : TYP. 2%)

Date code (2 digit)

1st digit				2nd digit	
Year of production				Month of production	
A.D.	Mark	A.D	Mark	Month	Mark
1990	A	2002	P	January	1
1991	B	2003	R	February	2
1992	C	2004	S	March	3
1993	D	2005	T	April	4
1994	E	2006	U	May	5
1995	F	2007	V	June	6
1996	H	2008	W	July	7
1997	J	2009	X	August	8
1998	K	2010	A	September	9
1999	L	2011	B	October	O
2000	M	2012	C	November	N
2001	N	⋮	⋮	December	D

repeats in a 20 year cycle

Factory identification mark

Factory identification Mark	Country of origin
no mark	Japan
■	
◢	Indonesia
◥	China

* This factory marking is for identification purpose only.
Please contact the local SHARP sales representative to see the actural status of the production.

Rank mark

Refer to the Model Line-up table

■ Absolute Maximum Ratings

(T_a=25˚C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I_F	50	mA
Input	*1 Peak forward current	I_{FM}	1.0	A
Input	Reverse voltage	V_R	6	V
Input	Power dissipation	P	70	mW
Output	Collector-emitter voltage	V_{CEO}	70	V
Output	Emitter-collector voltage	V_{ECO}	0.1	V
Output	Collector current	I_C	30	mA
Output	Collector power dissipation	P_C	150	mW
Total power dissipation		P_{tot}	200	mW
*2 Isolation voltage		$V_{iso\ (rms)}$	5.0	kV
Operating temperature		T_{opr}	−30 to +100	˚C
Storage temperature		T_{stg}	−55 to +125	˚C
*3 Soldering temperature		T_{sol}	260	˚C

*1 Pulse width≤100μs, Duty ratio : 0.001
*2 40 to 60%RH, AC for 1 minute, f=60Hz
*3 For 10s

■ Electro-optical Characteristics

(T_a=25˚C)

			Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage			V_F	I_F=20mA	–	1.2	1.4	V
Input	Peak forward voltage			V_{FM}	I_{FM}=0.5A	–	–	3.0	V
Input	Reverse Current			I_R	V_R=4V	–	–	10	μA
Input	Terminal capacitance			C_t	V=0, f=1kHz	–	30	250	pF
Output	Collector dark current			I_{CEO}	V_{CE}=50V, I_F=0	–	–	100	nA
Output	*4 Collector-emitter breakdown voltage			BV_{CEO}	I_C=0.1mA, I_F=0	70	–	–	V
Transfer charac-teristics	Collector current			I_C	I_F=5mA, V_{CE}=5V	2.5	–	20	mA
Transfer charac-teristics	Collector-emitter saturation voltage			$V_{CE\ (sat)}$	I_F=20mA, I_C=1mA	–	0.15	0.35	V
Transfer charac-teristics	Isolation resistance			R_{ISO}	DC500V, 40 to 60%RH	5×10^{10}	10^{11}	–	Ω
Transfer charac-teristics	Floating capacitance			C_f	V=0, f=1MHz	–	0.6	1.0	pF
Transfer charac-teristics	Response time	Not saturated	Rise time	t_r	V_{CE}=2V, I_C=2mA, R_L=100Ω	–	3	20	μs
Transfer charac-teristics	Response time	Not saturated	Fall time	t_f	V_{CE}=2V, I_C=2mA, R_L=100Ω	–	2	10	μs
Transfer charac-teristics	Response time	Saturated 1	Turn-on time	t_{on}	V_{CC}=5V, I_C=20mA, R_L=10kΩ	–	2	13	μs
Transfer charac-teristics	Response time	Saturated 1	Storage time	t_s	V_{CC}=5V, I_C=20mA, R_L=10kΩ	–	9	50	μs
Transfer charac-teristics	Response time	Saturated 1	Turn-off time	t_{off}	V_{CC}=5V, I_C=20mA, R_L=10kΩ	–	23	90	μs
Transfer charac-teristics	Response time	Saturated 2	Turn-on time	t_{on}	V_{CC}=5V, I_C=20mA, R_L=100kΩ	–	3	13	μs
Transfer charac-teristics	Response time	Saturated 2	Storage time	t_s	V_{CC}=5V, I_C=20mA, R_L=100kΩ	–	10	50	μs
Transfer charac-teristics	Response time	Saturated 2	Turn-off time	t_{off}	V_{CC}=5V, I_C=20mA, R_L=100kΩ	–	27	100	μs

*4 The collector-emitter voltage has negative resistance characteristics since this device has built-in base-emitter resistor.
Therefore, please be careful not to provide the voltage that goes beyond absolute maximum ratings.

■ Model Line-up

Lead Form	Through-Hole	SMT Gullwing		Rank mark	I_C [mA] (I_F=5mA, V_{CE}=5V, T_a=25˚C)
Package	100pcs/sleeve	100pcs/sleeve	2000pcs/reel		
Model No.	**PC81100NSZ0F**	**PC81100NIZ0F**	**PC81100NIP0F**	with or without	2.5 to 20.0
	PC81101NSZ0F	**PC81101NIZ0F**	**PC81101NIP0F**	A	3.0 to 6.0
	PC81102NSZ0F	**PC81102NIZ0F**	**PC81102NIP0F**	B	5.0 to 10.0
	PC81103NSZ0F	**PC81103NIZ0F**	**PC81103NIP0F**	C	7.5 to 15.0
	PC81105NSZ0F	**PC81105NIZ0F**	**PC81105NIP0F**	A or B	3.0 to 10.0
	PC81106NSZ0F	**PC81106NIZ0F**	**PC81106NIP0F**	B or C	5.0 to 15.0
	PC81108NSZ0F	**PC81108NIZ0F**	**PC81108NIP0F**	A, B or C	3.0 to 15.0

Please contact a local SHARP sales representative to inquire about production status.

Fig.1 Forward Current vs. Ambient Temperature

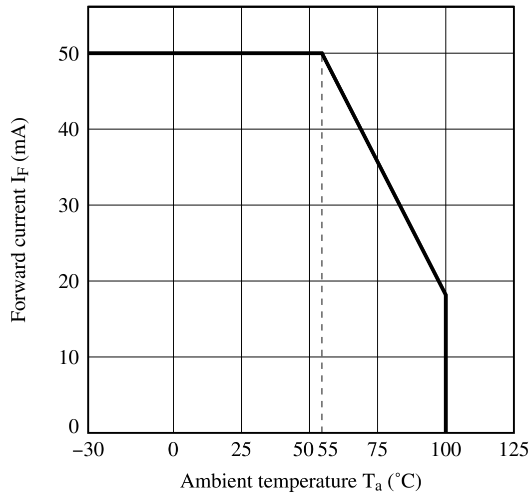


Fig.2 Diode Power Dissipation vs. Ambient Temperature

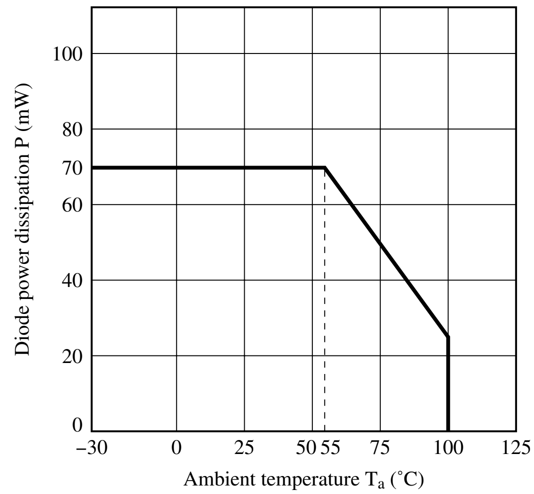


Fig.3 Collector Power Dissipation vs. Ambient Temperature

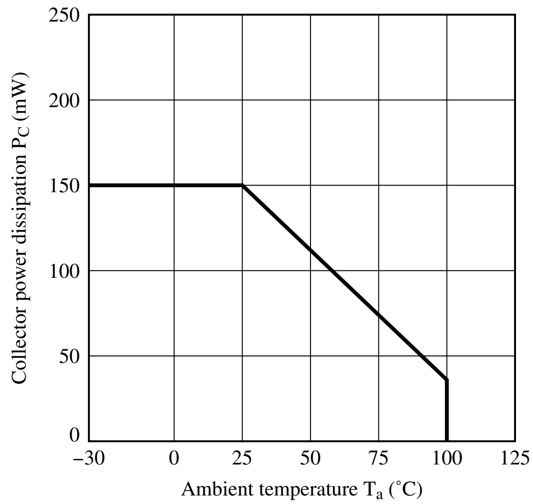


Fig.4 Total Power Dissipation vs. Ambient Temperature

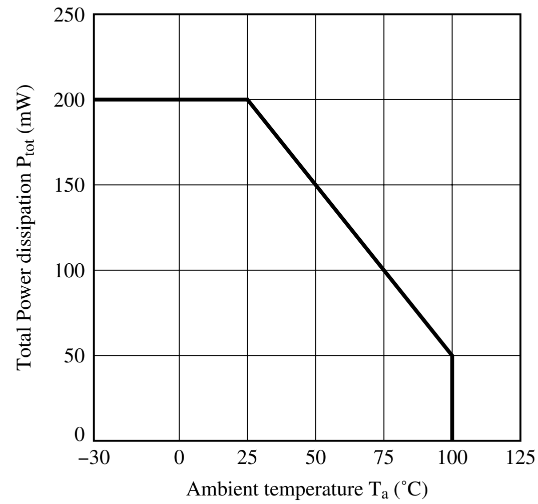


Fig.5 Peak Forward Current vs. Duty Ratio

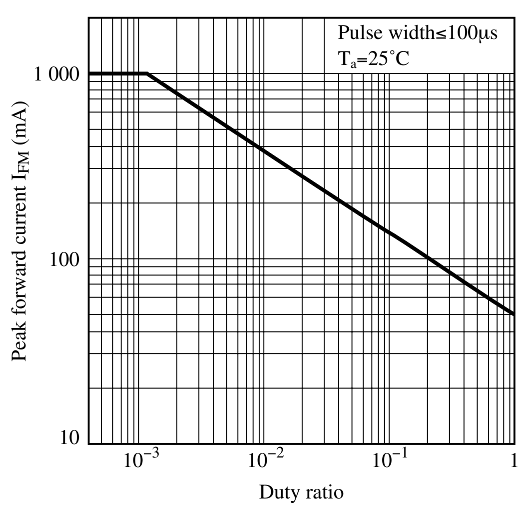


Fig.6 Forward Current vs. Forward Voltage

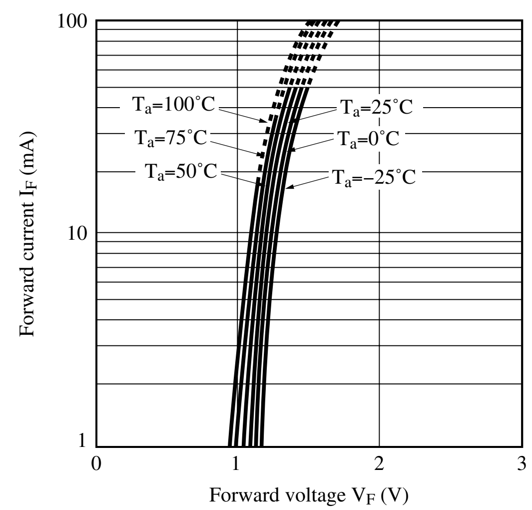


Fig.7 Current Transfer Ratio vs. Forward Current

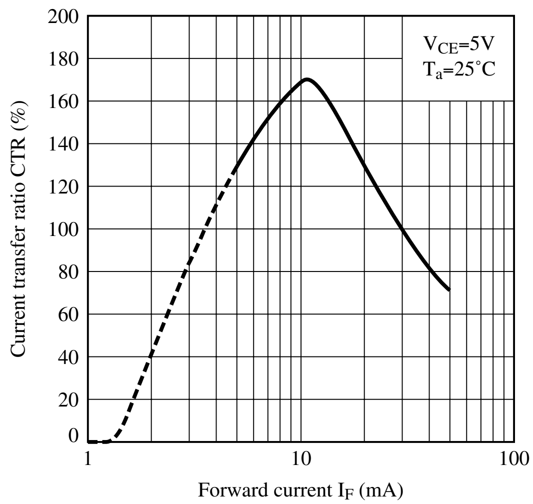


Fig.8 Collector Current vs. Collector-emitter Voltage

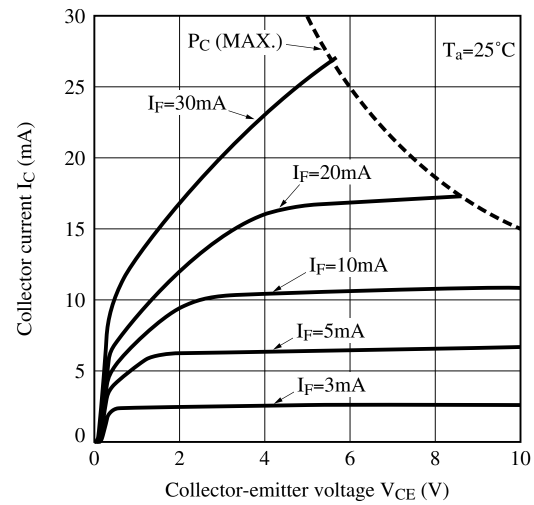


Fig.9 Relative Current Transfer Ratio vs. Ambient Temperature

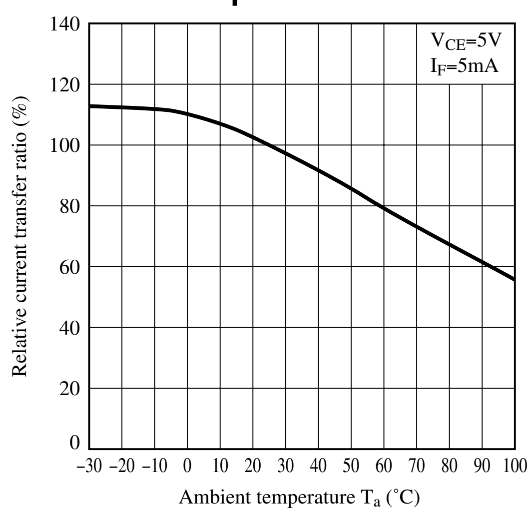


Fig.10 Collector - emitter Saturation Voltage vs. Ambient Temperature

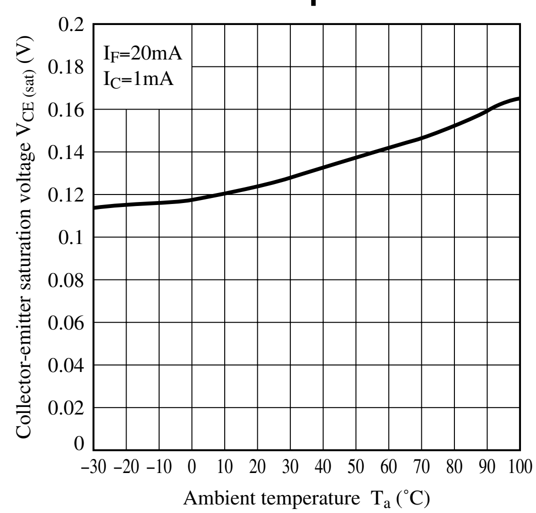


Fig.11 Collector Dark Current vs. Ambient Temperature

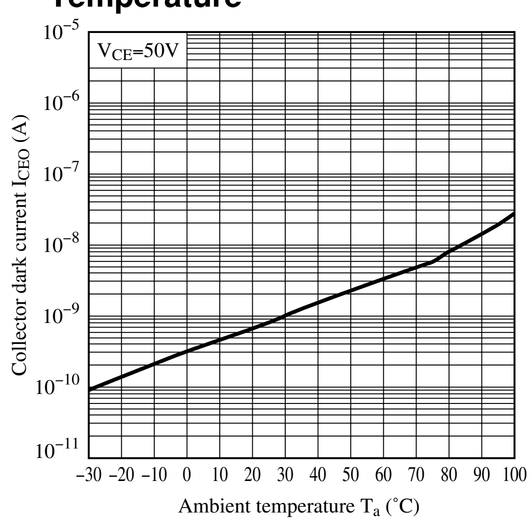


Fig.12 Response Time vs. Load Resistance (saturation region)

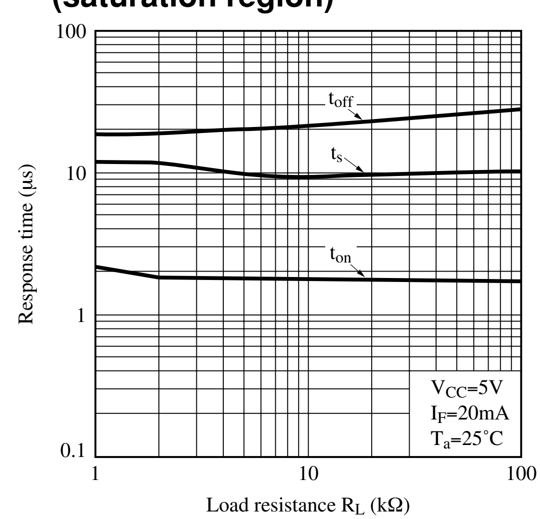


Fig.13 Response Time vs. Load Resistance (active region)

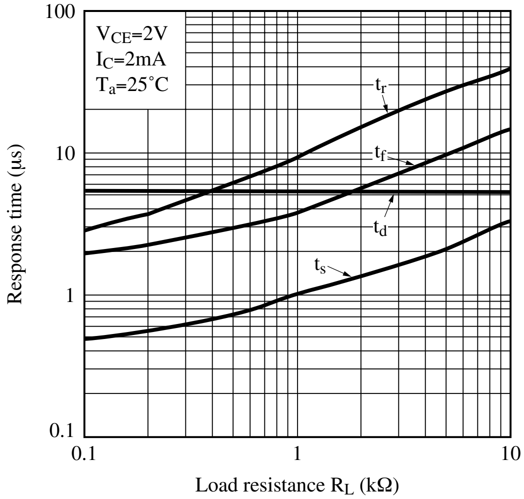
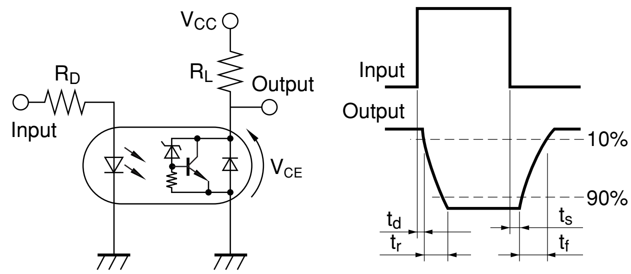


Fig.14 Test Circuit for Response Time



Please refer to the conditions in Fig.12 and Fig.13

Fig.15 Frequency Response

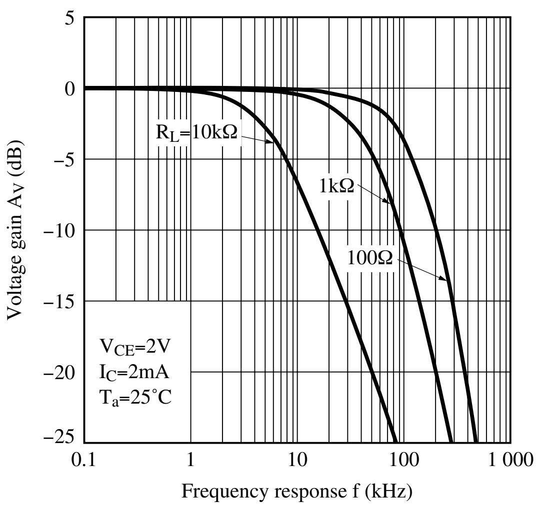
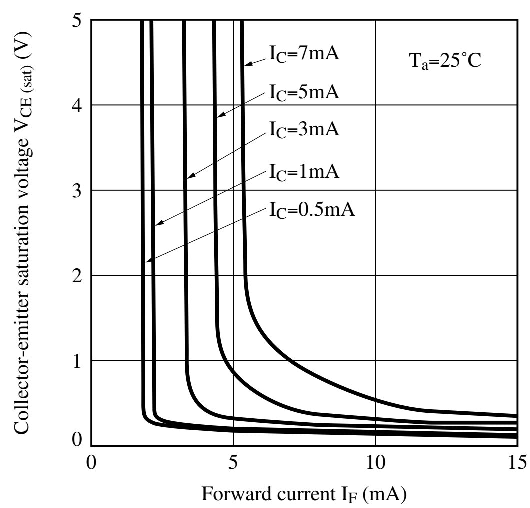


Fig.16 Collector-emitter Saturation Voltage vs. Forward Current



Remarks : Please be aware that all data in the graph are just for reference and not for guarantee.

■ Design Considerations

● Design guide

While operating at I_F<5.0mA, CTR variation may increase.
Please make design considering this fact.

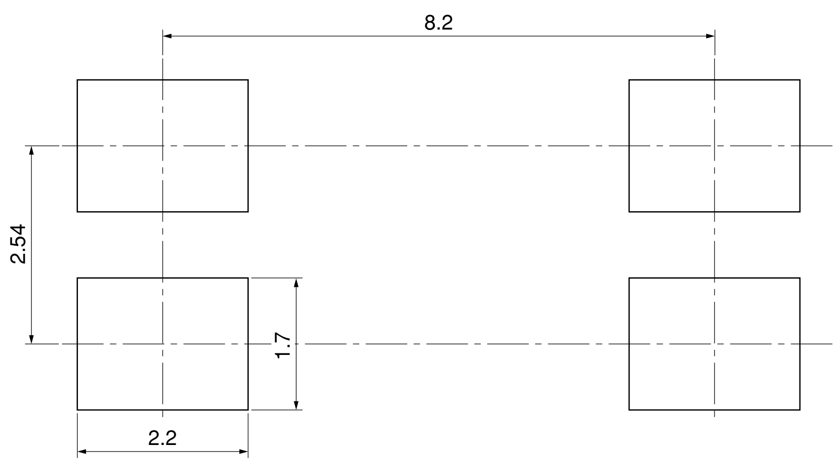
This product is not designed against irradiation and incorporates non-coherent IRED.

The collector-emitter voltage has negative resistance characteristics since this device has built-in base-emitter resistor.
Therefore, please be careful not to provide the voltage that goes beyond absolute maximum ratings.

● Degradation

In general, the emission of the IRED used in photocouplers will degrade over time.
In the case of long term operation, please take the general IRED degradation (50% degradation over 5 years) into the design consideration.

● Recommended Foot Print (reference)



(Unit : mm)

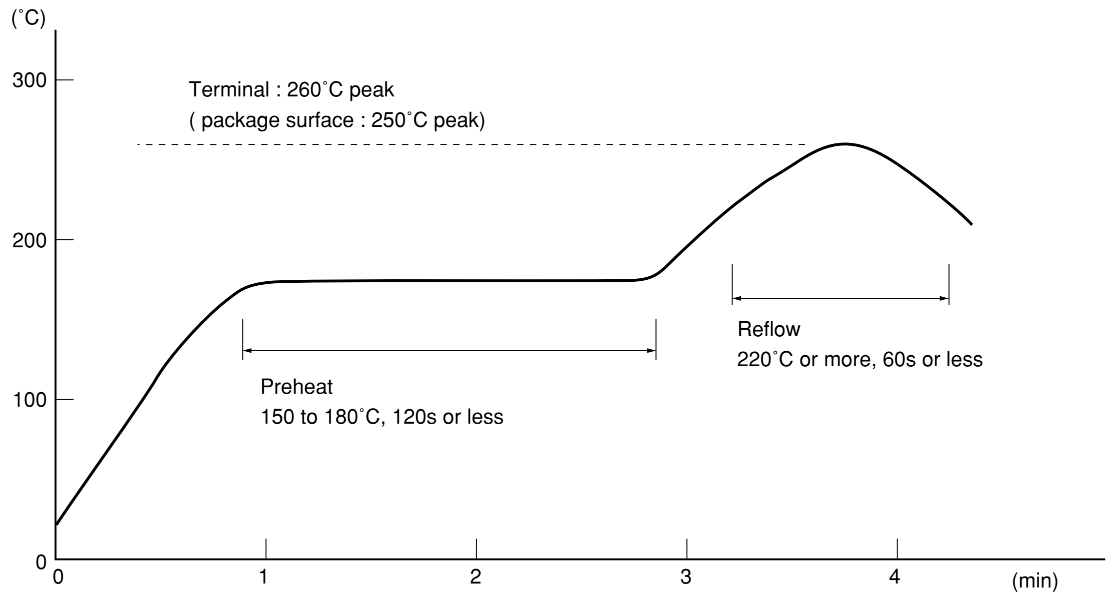
☆ For additional design assistance, please review our corresponding Optoelectronic Application Notes.

■ Manufacturing Guidelines

● Soldering Method

Reflow Soldering:

Reflow soldering should follow the temperature profile shown below.
Soldering should not exceed the curve of temperature profile and time.
Please don't solder more than twice.



Flow Soldering :

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 270˚C and within 10s.
Preheating is within the bounds of 100 to 150˚C and 30 to 80s.
Please don't solder more than twice.

Hand soldering

Hand soldering should be completed within 3s when the point of solder iron is below 400˚C.
Please don't solder more than twice.

Other notices

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.

● Cleaning instructions

Solvent cleaning:

Solvent temperature should be 45˚C or below Immersion time should be 3 minutes or less

Ultrasonic cleaning:

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.
Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

Recommended solvent materials:

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol
In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packaging resin.

● Presence of ODC

This product shall not contain the following materials.
And they are not used in the production process for this product.
Regulation substances : CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.

This product shall not contain the following materials banned in the RoHS Directive (2002/95/EC).

- Lead, Mercury, Cadmium, Hexavalent chromium, Polybrominated biphenyls (PBB), Polybrominated diphenyl ethers (PBDE).

■ Package specification

● Sleeve package

Package materials

Sleeve : HIPS (with anti-static material)

Stopper : Styrene-Elastomer

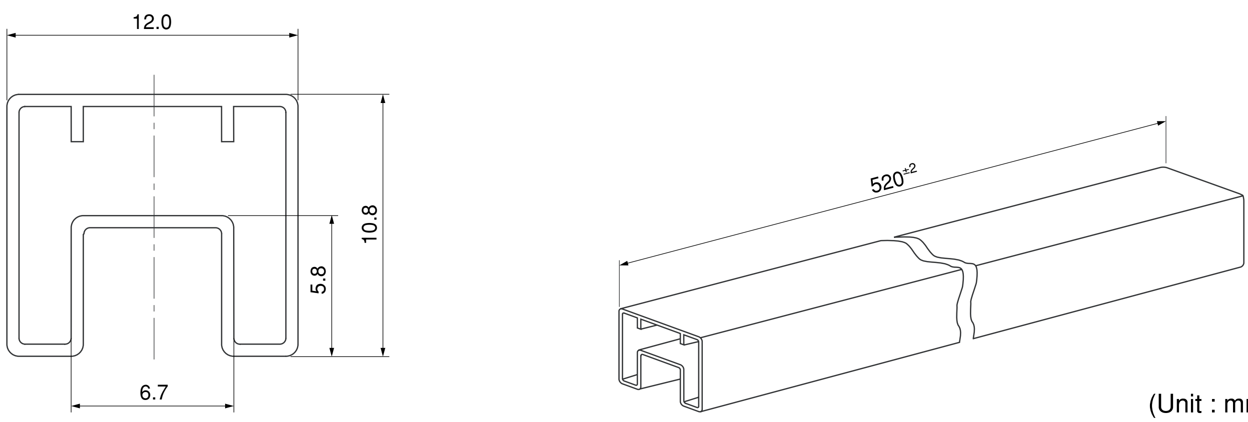
Package method

MAX. 100pcs of products shall be packaged in a sleeve. Both ends shall be closed by tabbed and tabless stoppers.

The product shall be arranged in the sleeve with its anode mark on the tabless stopper side.

MAX. 20 sleeves in one case.

Sleeve outline dimensions



(Unit : mm)

● Tape and Reel package

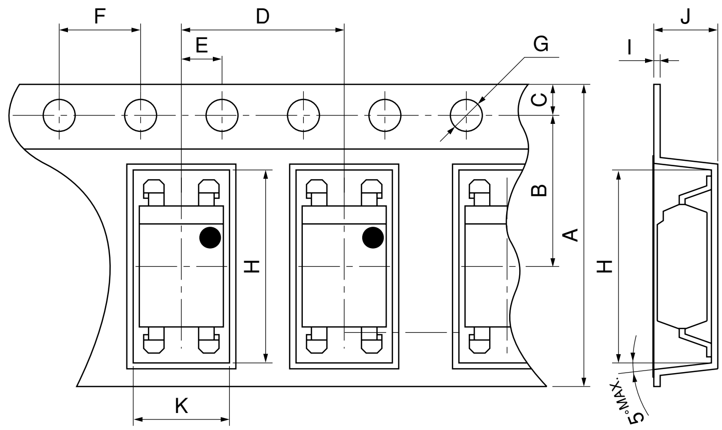
Package materials

Carrier tape : PS

Cover tape : PET (three layer system)

Reel : PS

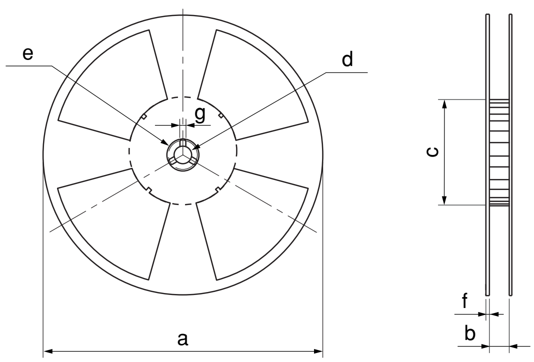
Carrier tape structure and Dimensions



Dimensions List (Unit : mm)

A	B	C	D	E	F	G
$16.0^{\pm0.3}$	$7.5^{\pm0.1}$	$1.75^{\pm0.1}$	$8.0^{\pm0.1}$	$2.0^{\pm0.1}$	$4.0^{\pm0.1}$	$\phi 1.5^{+0.1}_{-0}$
H	I	J	K			
$10.4^{\pm0.1}$	$0.4^{\pm0.05}$	$4.2^{\pm0.1}$	$5.1^{\pm0.1}$			

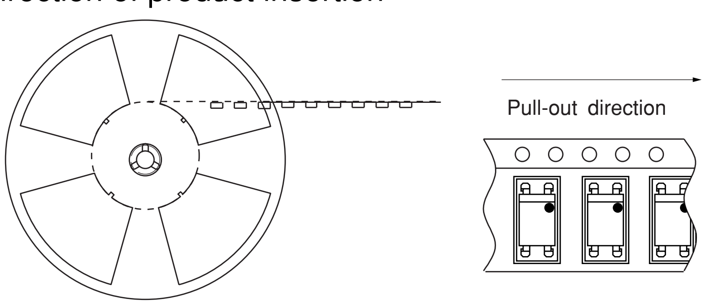
Reel structure and Dimensions



Dimensions List (Unit : mm)

a	b	c	d
330	$17.5^{\pm1.5}$	$100^{\pm1.0}$	$13^{\pm0.5}$
e	f	g	
$23^{\pm1.0}$	$2.0^{\pm0.5}$	$2.0^{\pm0.5}$	

Direction of product insertion



[Packing : 2 000pcs/reel]

■ Important Notices

· The circuit application examples in this publication are provided to explain representative applications of SHARP devices and are not intended to guarantee any circuit design or license any intellectual property rights. SHARP takes no responsibility for any problems related to any intellectual property right of a third party resulting from the use of SHARP's devices.

· Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device. SHARP reserves the right to make changes in the specifications, characteristics, data, materials, structure, and other contents described herein at any time without notice in order to improve design or reliability. Manufacturing locations are also subject to change without notice.

· Observe the following points when using any devices in this publication. SHARP takes no responsibility for damage caused by improper use of the devices which does not meet the conditions and absolute maximum ratings to be used specified in the relevant specification sheet nor meet the following conditions:

(i) The devices in this publication are designed for use in general electronic equipment designs such as:

--- Personal computers
--- Office automation equipment
--- Telecommunication equipment [terminal]
--- Test and measurement equipment
--- Industrial control
--- Audio visual equipment
--- Consumer electronics

(ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection with equipment that requires higher reliability such as:

--- Transportation control and safety equipment (i.e., aircraft, trains, automobiles, etc.)
--- Traffic signals
--- Gas leakage sensor breakers
--- Alarm equipment
--- Various safety devices, etc.

(iii) SHARP devices shall not be used for or in connection with equipment that requires an extremely high level of reliability and safety such as:

--- Space applications
--- Telecommunication equipment [trunk lines]
--- Nuclear power control equipment
--- Medical and other life support equipment (e.g., scuba).

· If the SHARP devices listed in this publication fall within the scope of strategic products described in the Foreign Exchange and Foreign Trade Law of Japan, it is necessary to obtain approval to export such SHARP devices.

· Contact and consult with a SHARP representative if there are any questions about the contents of this publication.